

OH921

HIGH SENSITIVITY CMOS HALL-EFFECT LATCH

Order Information

Package	Temperature Range	Part Number	Marking ID	Packing Type
TO92S-3	-40 to 125°C	OH921-T	920	Bulk
SOT23-3	-40 to 125°C	OH921-S	GS6	Tape & Reel

General Description:

The OH921 is a Hall-effect latch designed in mixed signal CMOS technology. It is quite suitable for use in automotive, industrial and consumer applications. Superior high-temperature performance is made possible through dynamic offset cancellation, which reduces the residual offset voltage normally caused by device over-molding, temperature dependencies, and thermal stress. The device integrates a voltage regulator, Hall-voltage generator, small-signal amplifier, chopper stabilization, schmitt trigger, and is directly drivable by the output.



Features

- Wide Operating Voltage Range from 3.5 to 24V
- Symmetrical Switch Points
- Chopper-stabilized Amplifier Stage
- Superior Temperature Stability
- Compact Size
- Built-in Pull-up Resistor
- ESD Rating: 3500V (Human Body Model)

Applications

- Brushless DC Motor Commutation
- Brushless DC Fan
- Solid-state Switch
- Revolution Counting
- Speed Detection
- High Sensitivity and Unconnected Switch

Absolute Maximum Ratings (T_A=25°C)

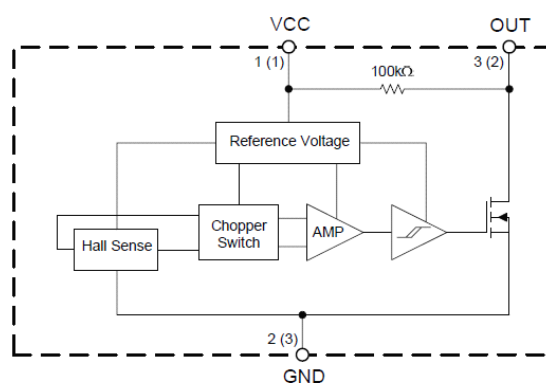
Supply Voltage V_{CC}.....3.5-28V

Output Current I_O.....25mA

Operating Temperature Range T_A-50~150°C

Storage Temperature Range T_S-65~150°C

Functional Block Diagram



A (B)
A for TO-92S-3
B for SOT-23-3

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Electrical Characteristics

V_{CC} = 12V, T_A = 25°C, unless otherwise specified

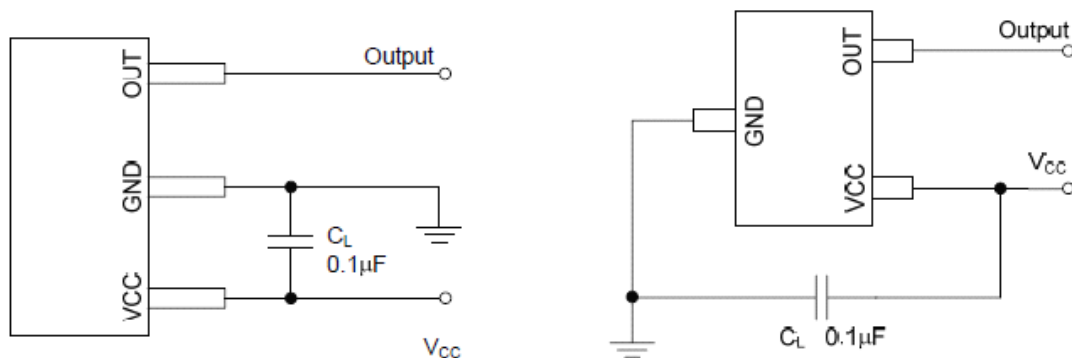
Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Supply Voltage	V _{CC}		3.5	12	24	V
Output Saturation Voltage	V _{SAT}	I _{OUT} = 20mA, B > B _{OP}	-	185	500	mV
Output Leakage Current	I _{LEAKAGE}	V _{CC} = V _{OUT} = 24V, B < B _{RP}	-	0.1	10	μA
Supply Current	I _{CC}	V _{CC} = 12V	-	3	5	mA
Output Rise Time	t _r	CL = 20pF	-	0.4	2	μS
Output Falling Time	t _f		-	0.4	2	μS

Magnetic Characteristics

V_{CC} = 12V, T_A = 25°C, (1mT = 10 Gauss)

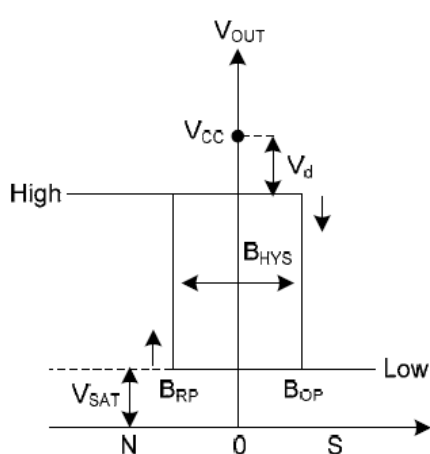
Parameter	symbol	Value			Unit
		Min	Typ	Max	
Operate Point	B _{OP}	0.5	2.2	4	mT
Release Point	B _{RP}	-4	-2.2	-0.5	mT
Hysteresis	B _H	-	4.5	-	mT

Typical Application:

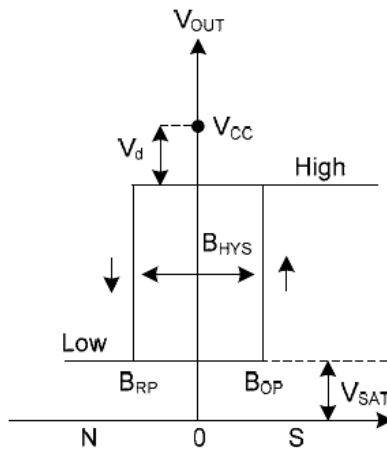


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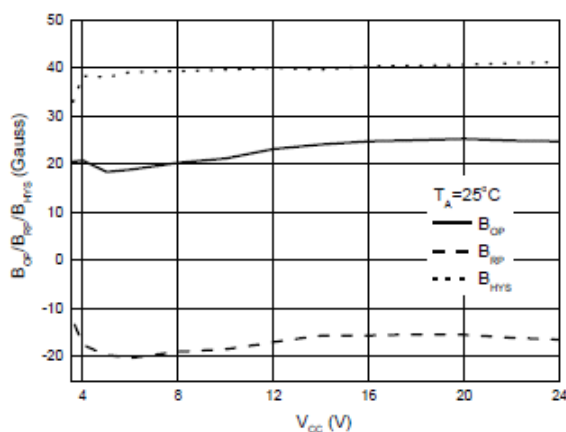
For TO-92S-3



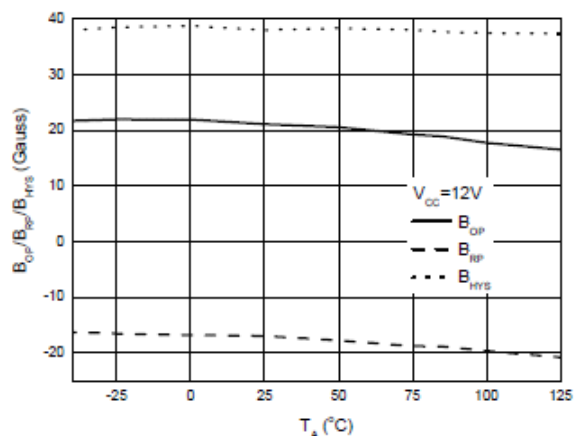
For SOT-23-3

Package Type	Parameter	Test condition	Output
TO-92S-3	South Pole	$B > B_{OP}$	Low
	North Pole	$B < B_{RP}$	High
SOT-23-3	South Pole	$B > B_{OP}$	High
	North Pole	$B < B_{RP}$	Low

Typical Performance Characteristics



B_{OP}/B_{RP}/B_{HYS} vs. V_{CC}



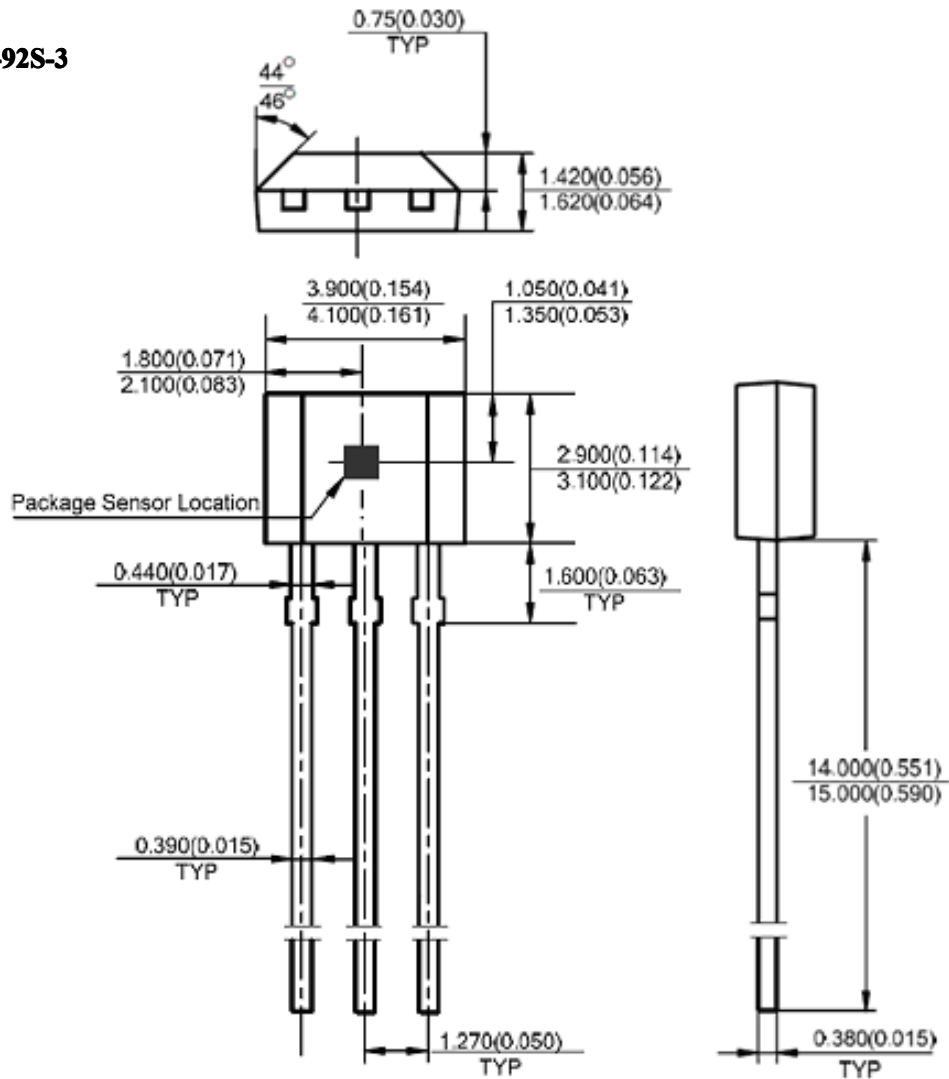
B_{OP}/B_{RP}/B_{HYS} vs. T_A

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Mechanical Dimension unit:mm(inch)

TO-92S-3



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SOT23-3

